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PAPER

## Enhanced light harvesting in bulk heterojunction photovoltaic devices with shape-controlled Ag nanomaterials: Ag nanoparticles *versus* Ag nanoplates†

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Enhanced power conversion efficiency (PCE(%)) with improved optical path length from two types of shape controlled silver (Ag) materials (Ag nanoplates *versus* Ag nanoparticles (NPs)) was studied in poly(3-hexylthiophene) (P3HT)/[6,6]-phenyl C<sub>71</sub> butyric acid methyl-ester (PC<sub>71</sub>BM) or poly[N-9''-hepta-decanyl-2,7-carbazole-alt-5,5-(4',7'-di-2-thienyl-2',1',3'-benzothiadiazole)] (PCDTBT)/[6,6]-phenyl C<sub>71</sub> butyric acid methyl-ester (PC<sub>71</sub>BM) bulk heterojunction (BHJ) devices. The Ag nanoplates and Ag NPs can be synthesized by simple solution polyol chemistry with well defined size and shape. A BHJ with a 0.5 wt% optimized blend ratio of Ag nanoplates shows improved cell performance and photo-current density than a BHJ with Ag NPs owing to the enhanced light absorption with the results of an excitation of localized surface plasmon and efficient light scattering by the Ag nanoplates embedded BHJ film. When the BHJ is combined with the Ag nanoplates at an optimized ratio of 0.5 wt%, the PCE (%) increases from 3.2% to 4.4% in P3HT/PC<sub>71</sub>BM, and from 5.9% to 6.6% in PCDTBT/PC<sub>71</sub>BM BHJ devices.

### Introduction

Bulk heterojunction (BHJ) photovoltaic devices based on polymer–fullerene have been widely researched on account of their numerous advantages. Specifically, they can be fabricated in a large area with a simple method; they are flexible low-cost devices that involve a roll-to-roll manufacturing process; and their industrial application has great potential for the future.<sup>1–8</sup> The efficiency of photovoltaic devices has gradually increased from 2% to 8% as a result of various meaningful studies. The studies have focused on diverse aspects, such as solvent additives,<sup>9</sup> thermal treatment,<sup>10,11</sup> newly designed donor–acceptor polymers,<sup>12</sup> donor–acceptor blend ratios,<sup>13,14</sup> efficient nanopatterned structural effects (tandem or regular patterns),<sup>15–17</sup> the plasmonic embedded nanoparticles (NPs) effect,<sup>18–21</sup> and other novel processes (involving transfers and printing).<sup>22,23</sup>

Silver (Ag) metal NPs exhibit a localized surface plasmon resonance (LSPR) that is coupled tightly with the incident light. Moreover, metallic NPs larger than 10 nm can scatter and reflect the incident light, thereby increasing the length of the optical path within the BHJ active layer film. Especially, the shape and size of Ag materials can be easily controlled, have efficient reproducibility and higher yields than other metallic NPs. Thus, the embedding of metal NPs in BHJ film offers the possibility of enhanced optical absorption. The power conversion efficiency (PCE (%)) leads to a corresponding enhancement of the photo-generation of mobile carriers. Hence, when Ag is embedded in BHJ films, the different shapes of the Ag particles produce dissimilar absorption properties and different levels of reflectivity.<sup>20,21</sup>

In a BHJ solar cell, the active layer (which has the maximum efficiency) generally has a thickness of less than 200 nm. One of the major roles of Ag nanomaterials in a BHJ solar cells is its effective light scattering effect. To maximize the effectiveness of Ag nanomaterials, researchers generally prefer to use large rather than small materials. Unfortunately, the restricted thickness of BHJ film makes it impossible to use Ag nanomaterial that is larger than 200 nm. However, a 2 dimensional nanostructure with a high aspect ratio can overcome this constraint if the material can be spread horizontally on a target substrate during the spin-coating process.<sup>21</sup> This assumption is reasonable because the intensification of the van der Waals interactions between the Ag nanoplate surface and the target surface stem primarily from the structural characteristics of the 2D nanosheets.<sup>24</sup> Therefore, when the Ag nanoplates are sheared

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during the spin-coating of the poly(3,4-ethylene dioxythiophene) : poly(styrene sulphonate) (PEDOT : PSS) surface, they tend to be oriented horizontally on the PEDOT : PSS surface.

This research compares two different shape-controlled Ag materials (Ag NPs and Ag nanoplates) embedded in BHJ photovoltaic cells fabricated with either poly(3-hexylthiophene) (P3HT)/[6,6]-phenyl C<sub>71</sub> butyric acid methyl-ester (PC<sub>71</sub>BM) or poly[*N*-9'-hepta-decanyl-2,7-carbazole-alt-5,5-(4',7'-di-2-thienyl-2',1',3'-benzothiadiazole)] (PCDTBT)/[6,6]-phenyl C<sub>71</sub> butyric acid methyl-ester (PC<sub>71</sub>BM). When they are embedded in the BHJ, the Ag NPs and Ag nanoplates have different absorption spectra and optical reflectance levels, and these differences strongly affect the cell. To compare and investigate how the shape of Ag materials affects the performance of photovoltaic devices, we blended the Ag NPs and Ag nanoplates into a BHJ solution with various weight ratios ranging from 0.1 wt% to 1 wt%. Ag nanoplates are also well dispersed in the BHJ film after the spin-coating process. At an optimized blend ratio of 0.5 wt% with Ag nanoplates in BHJ film, the PCE increased from 3.2% to 4.4% for the P3HT/PC<sub>71</sub>BM and from 5.9% to 6.6% for the PCDTBT/PC<sub>71</sub>BM, owing to the light-trapping effect and the enhanced optical path length in the active layer.

## Experimental

### Synthesis of Ag NPs

We used AgNO<sub>3</sub> (Aldrich) as the precursor of the Ag NPs and poly(vinylpyrrolidone) (PVP) (Aldrich, Mw = 55 000) as the surfactant. In a typical synthesis, we mixed 3.0 mL of a 94 mM sample of AgNO<sub>3</sub>, 3.0 mL of a 147 mM sample of PVP, and 6 mL of polyol. We then heated the mixture at 140 °C for 1 h. To control the 30 nm-sized Ag NPs, we used an optimized 1,5-pentanediol (PtD: Aldrich) solvent. The smaller NPs were synthesized in a more viscous medium. For example, the polyol viscosity increases as the hydrocarbon chain is elongated in the order of PtD > 1,4-butanediol (BD: Sigma Aldrich) > PrD 1,2-propanediol (PrD: Sigma Aldrich). The size of the synthesized NPs then decreases in the order of PrD (60 nm) > BD (40 nm) > PtD (30 nm). Lastly, we added ethanol for the centrifugation process and then collected the synthesized Ag NPs in vials.

### Synthesis of Ag nanoplates

Ag nanoplates were synthesized *via* an aqueous-phase route, as reported elsewhere.<sup>25</sup> In a typical synthesis, we heated 8 mL of an aqueous solution containing PVP (Mw = 29 000, 100 mg, Aldrich) at 60 °C in air under magnetic stirring. In addition, AgNO<sub>3</sub> (95.8 mg, Aldrich) was dissolved in 3 mL of deionized water at room temperature. The aqueous solution of AgNO<sub>3</sub> was added to the PVP solution, and the reaction mixture was then aged at 60 °C in air for 21 h. After the synthesis, the product was collected by centrifugation, washed with ethanol to remove the excess PVP, and then re-dispersed in water.

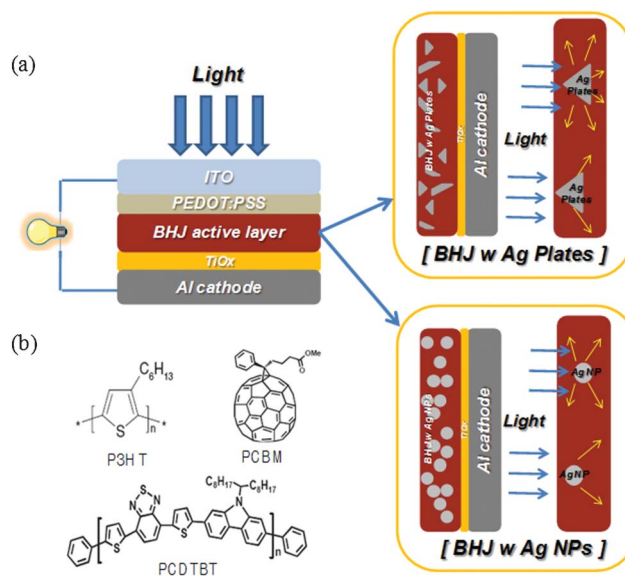
### Device fabrication

P3HT, PCBM and PCDTBT was purchased from Rieke Metal, Nano-C and 1-Material, respectively. Polymer solar cells based on P3HT/PC<sub>61</sub>BM, P3HT/PC<sub>71</sub>BM or PCDTBT/PC<sub>71</sub>BM with a blend of Ag materials from NPs or nanoplates were prepared as

shown in Fig. 1. Because of surface impurities, the ITO glass substrate was step by step cleaned with solvents of chloroform, acetone, and isopropanol, respectively with an ultra-sonic process. The ITO glass was then exposed to UV for 15 min to reform the surface before the spin-casting of PEDOT : PSS (Baytron PH) for 5000 rpm at 40 s. After the spin-casting of PEDOT : PSS, the substrate was baked at 140 °C for 10 min to evaporate the solvent. On top of the PEDOT/PSS layer, we made a 120 nm (P3HT/PCBM for 2000 rpm at 20 s) or an 100 nm (PCDTBT/PC<sub>71</sub>BM for 5000 rpm at 40 s) BHJ active layer with Ag NPs or nanoplates with a weight ratio of 0.1 wt%, 0.5 wt%, and 1 wt% in a mixed solution of P3HT/PCBM (1 : 0.8) in a chlorobenzene solvent or PCDTBT/PC<sub>71</sub>BM (1 : 4) in 1,2-dichlorobenzene : chlorobenzene (3 : 1), respectively. The reference device was composed of a plain donor-acceptor BHJ without any Ag materials. The BHJ films were dried at 80 °C for 10 min in a glove box. The TiO<sub>x</sub> interlayer was then spin-coated in air at room temperature to a thickness of 10 nm (5000 rpm, 40 s). An Al metal cathode was thermally deposited by means of an evaporator to a thickness of 100 nm at a pressure of 5.0 × 10<sup>-6</sup> Torr. The device efficiency levels were measured with a solar simulator (Air Mass 1.5 Global) at an intensity of 1000 Wm<sup>-2</sup>. A Keithley 236 source measure unit was also used to characterize the voltage-current density of each device. All the cell areas were accurately measured by the SV-35 video microscope system (SOMETECH). The surface morphology of the BHJ film was analyzed with the aid of a scanning electron microscope (SEM, FEI Sirion XL 30) and an atomic force microscope (Veeco, USA; D3100).

## Results and discussion

Fig. 1(a) shows the schematic diagram of the devices with two different shapes of Ag materials of NPs or nanoplates. Fig. 1(b) reveals the chemical structures of the donor polymers P3HT and PCDTBT, and acceptor polymer PC<sub>71</sub>BM.

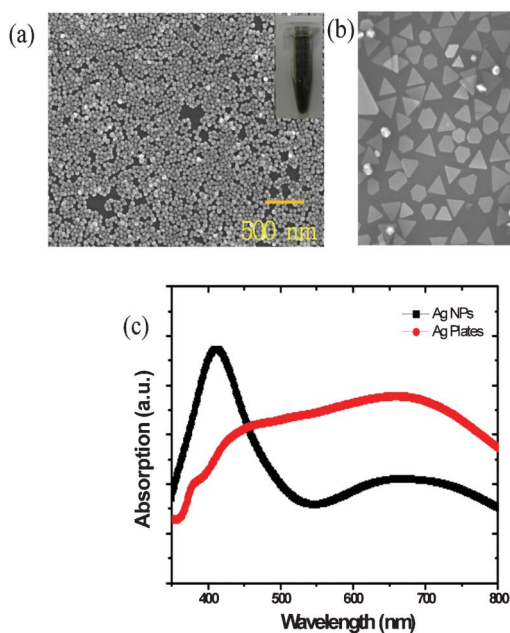


**Fig. 1** (a) A schematic diagram of the devices with two different Ag materials (Ag nanoplates and Ag NPs); (b) the chemical structures of P3HT and PCDTBT of the donor and PC<sub>71</sub>BM of the acceptor.

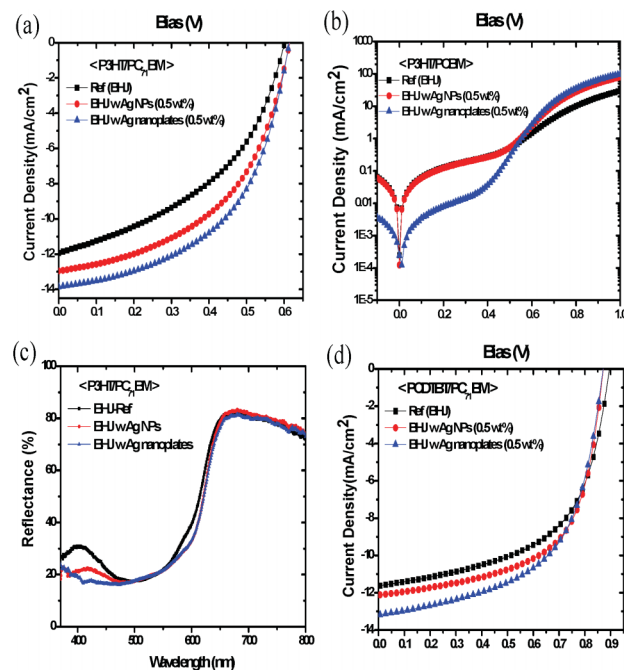
The shape of the synthesized Ag materials was confirmed with SEM images. As shown in Fig. 2(a) and Fig. 2(b), the NP diameter is  $\sim 40$  nm and the nanoplate diameter is  $\sim 200$  nm to 500 nm. The UV-visible absorption spectra of Fig. 2(c) show that the synthesized Ag NPs have an maximum absorption peak near 420 nm; they also show that the nanoplates have a very broad peak of 400 nm to 800 nm. The analysis results from energy dispersive spectroscopy in Fig. S1 (ESI†) show that the synthesized nanoplates were composed of an Ag element. Furthermore, the different shapes of the Ag materials have a different colour when Ag is dispersed in ethanol. The Ag NPs are dark green and the Ag nanoplates are light gray. For these reasons, the dissimilar shape of the synthesized Ag materials produces different absorption behaviour and the reflective phenomena appear to depend on the shape and size of Ag. Note that the Ag nanoplates can efficiently reflect the incident solar light because the particles are large and the aspect ratio is greater than 50.

Fig. 3(a) shows the photocurrent–voltage ( $J$ – $V$ ) curves of plain BHJ (P3HT/PC<sub>71</sub>BM) devices and BHJ devices embedded with Ag NPs or Ag nanoplates with a 0.5 wt% ratio *versus* the total weight of the donor–acceptor polymer mixtures.

The P3HT/PC<sub>71</sub>BM BHJ device without Ag materials has a PCE of 3.2%, an open-circuit voltage ( $V_{oc}$ ) of 0.60 V, a short-circuit current ( $J_{sc}$ ) of 11.93 mA cm<sup>-2</sup>, and a fill factor ( $FF$ ) of 0.44. In contrast, the BHJ devices with an optimized ratio of 0.5 wt% of Ag NPs or Ag nanoplates have an improved PCE level of 4.0% and 4.4%, respectively. The fact that the photocurrent density ( $J_{sc}$ ) increased from 11.93 mA cm<sup>-2</sup> (for the plain BHJ) to 13.85 mA cm<sup>-2</sup> (for the Ag nanoplates) is a key factor in the enhancement of the device performance. The series resistance of the plain BHJ (without Ag) was 8.95  $\Omega$  cm<sup>2</sup>, whereas that of the BHJ with Ag nanoplates was at a lower level of 2.94  $\Omega$  cm<sup>2</sup>.



**Fig. 2** (a) SEM images of the Ag NPs, and (b) Ag nanoplates. The inset figures show the Ag materials dispersed in an ethanol solvent (Ag NPs: dark green; Ag nanoplates: light gray). (c) UV-visible absorption spectra of Ag nanoparticles and Ag nanoplates.



**Fig. 3** (a) The  $J$ – $V$  curves of devices with the plain P3HT/PC<sub>71</sub>BM BHJ, the BHJ with Ag NPs, and the BHJ with Ag nanoplates from a ratio of 0.5 wt%. (b) The  $J$ – $V$  curves of devices with the plain P3HT/PC<sub>71</sub>BM BHJ, and the BHJ with Ag NPs (0.5 wt%) and nanoplates (0.5 wt%) in the dark current. (c) Diffuse reflectance spectra of the plain P3HT/PC<sub>71</sub>BM BHJ, the BHJ with Ag NPs (0.5 wt%), and the BHJ with Ag nanoplates (0.5 wt%) as a function of wavelength (nm). (d)  $J$ – $V$  curves of devices with the plain PCDTBT/PC<sub>71</sub>BM BHJ, the BHJ with Ag NPs, and the BHJ with Ag nanoplates for a ratio of 0.5 wt%.

This reduction, as shown in Fig. 3(b), appears to be associated with the higher short circuit currents. The overall device efficiency and average values are summarized in Table 1 and Fig. 4, respectively.

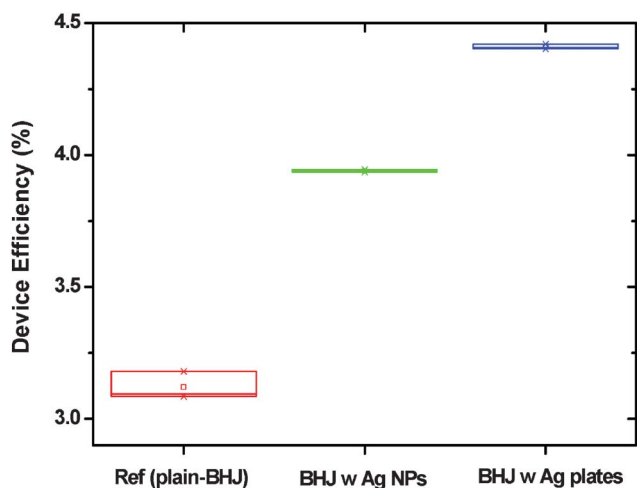
Note also that the ratio of the BHJ active layer and the Ag materials was optimized by varying the concentration from 0.1 wt% to 1 wt%. We used an optimized 0.5 wt% ratio between the active materials and the Ag materials. As shown in Fig. S2 (ESI†) and each inset table, the blending of the P3HT/PC<sub>61</sub>BM BHJ active layer with Ag NPs or nanoplates at a ratio of more than 0.5 wt% yields a  $FF$  value that is less than the  $FF$  value of the optimized device.

Fig. 5 shows SEM images of the three kinds of BHJ active layers. Fig. 5(a) shows the plain P3HT/PC<sub>71</sub>BM BHJ with a clear surface morphology. Fig. 5(b) and 5(c) show the BHJ with 40 nm Ag NPs (0.5 wt%) and the BHJ with Ag nanoplates (0.5 wt%), respectively. These images confirm that the Ag NPs and Ag nanoplates can be well dispersed yet retain their particular shape and size within the BHJ film. Fig. 5(d) shows that the Ag nanoplates were slightly tilted and twisted when blended with the BHJ solution and after the spin-coating process. Interestingly, the surface roughness of the blended film was unchanged when the BHJ was combined with Ag nanoplates. The atomic force microscopy (AFM) results in Fig. S3 (ESI†) confirm that the surface roughness of root mean square (rms) of the plain BHJ (6.9 nm) is similar to that of the Ag nanoplates (5.9 nm).

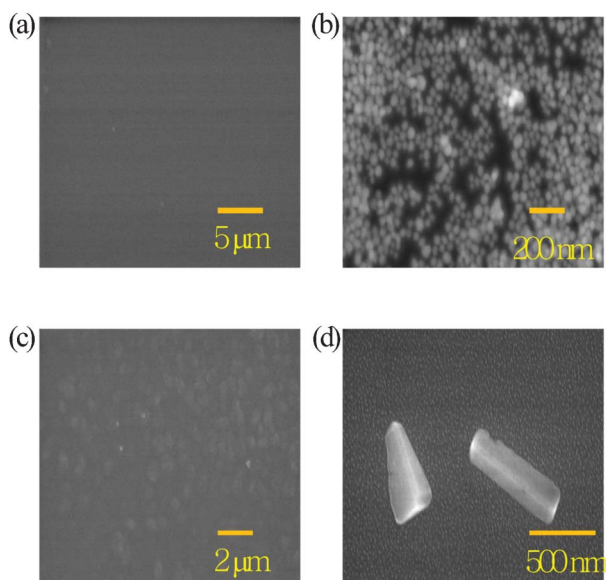


**Table 1** The efficiency levels of the devices with a plain P3HT/PC<sub>71</sub>BM BHJ or BHJ with Ag materials (Ag nanoparticles or Ag nanoplates with a ratio of 0.5 wt%), and a plain PCDTBT/PC<sub>71</sub>BM BHJ or BHJ with Ag nanoplates (0.5 wt%)

BHJ devices with or without Ag		$V_{oc}$ (V)	$J_{sc}$ (mA cm <sup>-2</sup> )	$FF$	Efficiency (%)
P3HT/PC <sub>71</sub> BM	BHJ (ref.)	0.60	11.93	0.44	3.2
	BHJ w/ Ag NPs (0.5 wt%)	0.62	12.95	0.50	4.0
	BHJ w/ Ag nanoplates (0.5 wt%)	0.61	13.85	0.52	4.4
PCDTBT/PC <sub>71</sub> BM	BHJ (ref.)	0.90	11.63	0.57	5.9
	BHJ w/ Ag NPs (0.5 wt%)	0.87	12.12	0.61	6.4
	BHJ w/ Ag nanoplates (0.5 wt%)	0.87	13.19	0.57	6.6



**Fig. 4** The average P3HT/PC<sub>71</sub>BM device efficiencies of plain BHJ (reference device), BHJ with Ag NPs, and BHJ with Ag nanoplates. The BHJ device with Ag nanoplates (4.41%, 0.61 V, 13.96 mA cm<sup>-2</sup>, 0.51) showed increased average power conversion efficiency, open circuit voltage (V), photo-current density (mA cm<sup>-2</sup>), and FF than the device of plain-BHJ (3.12%, 0.60 V, 12.33 mA cm<sup>-2</sup>, 0.42) and the BHJ with Ag NPs (3.94%, 0.61 V, 13.11 mA cm<sup>-2</sup>, 0.49).



**Fig. 5** SEM images of the active layer of (a) the plain P3HT/PC<sub>71</sub>BM BHJ and (b) the BHJ with Ag NPs (0.5 wt%); (c) low-resolution SEM image and (d) high-resolution SEM image of the BHJ with Ag nanoplates (0.5 wt%).

A BHJ film with Ag nanoplates may have superior absorption than the plain BHJ and BHJ with Ag NPs because it can scatter the incident light more effectively on account of the large particle size.<sup>4,20</sup> As indicated in the UV-visible absorption spectra (Fig. S4, ESI†), the shape of the Ag nanoplates causes the BHJ film with Ag nanoplates to show more enhanced light absorption than the pure BHJ film or the BHJ film embedded with Ag NPs. The diffuse reflectance spectra of incident light as a function of wavelengths resemble the absorption spectra in Fig. 3(c). This resemblance suggests that the length of the optical path within the BHJ film can be enhanced. Hence, the P3HT/PC<sub>71</sub>BM BHJ device with Ag nanoplates (0.5 wt%) has a higher level of optical absorbance than the plain P3HT/PC<sub>71</sub>BM BHJ or the BHJ with Ag NPs at reflectance wavelength of around 400 nm to 500 nm. The scattering effect of the Ag nanoplates increases the effective length of the optical path, which in turn increases the generation of electron-hole pairs.<sup>20</sup> The enhanced optical absorbance is closely related to the improved  $J_{sc}$  and PCE levels in the BHJ devices.

The ratio of Ag nanoplates was also optimized in another PCDTBT/PC<sub>71</sub>BM BHJ active layer to prove the positive effects of Ag nanoplates in universal BHJ devices. The value of  $FF$  remained 0.57, and the value of  $J_{sc}$  increased to a critical extent, from 11.63 mA cm<sup>-2</sup> to 13.19 mA cm<sup>-2</sup> as shown in Fig. 3(d). The BHJ device with Ag nanoplates showed increased average power conversion efficiency (more than ten samples were tested as shown in Fig. S5, ESI†) over the BHJ devices with Ag NPs and without Ag materials. Additionally, all cases of thick and thin active layer BHJ solar cells with Ag nanoplates revealed improved fill factor, PCE (%), and incident photon to current efficiency (IPCE) over the plain BHJ device as shown in Fig. S6 and Fig. S7 (ESI†).

## Conclusions

In conclusion, we have demonstrated the positive effects of Ag nanoplates in P3HT/PC<sub>71</sub>BM and PCDTBT/PC<sub>71</sub>BM BHJ photovoltaic devices. The BHJ embedded with Ag nanoplates has greater  $J_{sc}$  and PCE values than the plain BHJ and the BHJ with Ag NPs. These results are attributed to the fact that the active layer has an enhanced level of light absorption because the length of the optical path is increased by the efficient scattering and light trapping in the BHJ active films. We believe that the shape of a metal NP is a critical factor in maximizing the light scattering in BHJ solar cells. Finally, a BHJ active layer embedded with Ag nanoplates at a ratio of 0.5 wt% increases the PCE from 3.2% to 4.4% in a P3HT/PC<sub>71</sub>BM BHJ device and from 5.9% to 6.6% in a PCDTBT/PC<sub>71</sub>BM BHJ device.

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## References

- G. Yu, J. Gao, J. C. Hummelen, F. Wudl and A. J. Heeger, *Science*, 1995, **270**, 1789.
- S. H. Park, A. Roy, S. Beaupre, S. Cho, N. Coates, J. S. Moon, D. Moses, M. Leclerc, K. Lee and A. J. Heeger, *Nat. Photonics*, 2009, **3**, 297.
- A. J. Heeger, *Angew. Chem., Int. Ed.*, 2001, **40**, 2591.
- D. H. Wang, D. Y. Kim, K. W. Choi, J. H. Seo, S. H. Im, J. H. Park, O. O. Park and A. J. Heeger, *Angew. Chem., Int. Ed.*, 2011, **50**, 5519.
- G. Dennler, M. C. Scharber and C. J. Brabec, *Adv. Mater.*, 2009, **21**, 1323.
- D. H. Wang, D. G. Choi, O. O. Park and J. H. Park, *J. Mater. Chem.*, 2010, **20**, 4910.
- C. J. Brabec, S. Gowrisanker, J. J. M. Halls, D. Laird, S. Jia and S. P. Williams, *Adv. Mater.*, 2010, **22**, 3839.
- D. H. Wang, J. S. Moon, J. Seifert, J. Jo, J. H. Park, O. Park O and A. J. Heeger, *Nano Lett.*, 2011, **11**, 3163.
- C. V. Hoven, X.-D. Dang, R. C. Coffin, J. Peet, T.-Q. Nguyen and G. C. Bazan, *Adv. Mater.*, 2010, **22**, E63.
- Ma, C. Yang, X. Gong, K. H. Lee and A. J. Heeger, *Adv. Funct. Mater.*, 2005, **15**, 1617.
- C. J. Brabec, N. S. Sariciftci and J. C. Hummelen, *Adv. Funct. Mater.*, 2001, **11**, 15.
- L. Huo, J. Hou, S. Zhang, H.-Y. Chen and Y. Yang, *Angew. Chem., Int. Ed.*, 2010, **49**, 1500.
- D. H. Wang, J. K. Kim, O. O. Park and J. H. Park, *Energy Environ. Sci.*, 2011, **4**, 1434.
- N. D. Treat, M. A. Brady, G. Smith, M. F. Toney, E. J. Kramer, C. J. Hawker and M. L. Chabinyc, *Adv. Energy Mater.*, 2011, **1**, 82.
- S. Sista, M.-H. Park, Z. Hong, Y. Wu, J. Hou, W. L. Kwan, G. Li and Y. Yang, *Adv. Mater.*, 2010, **22**, 380.
- D. H. Wang, D. G. Choi, K. J. Lee, J. H. Park and O. O. Park, *Langmuir*, 2010, **26**, 9584.
- D. H. Wang, D. G. Choi, K. J. Lee, S. H. Im, O. O. Park and J. H. Park, *Org. Electron.*, 2010, **11**, 1376.
- H. A. Atwater and A. Polman, *Nat. Mater.*, 2010, **9**, 205.
- K. Kim and D. L. Carroll, *Appl. Phys. Lett.*, 2005, **87**, 203113.
- D. H. Wang, K. H. Park, J. H. Seo, J. Seifert, J. H. Jeon, J. H. Park, O. O. Park and A. J. Heeger, *Adv. Energy Mater.*, 2011, **1**, 766.
- C.-H. Kim, S.-H. Cha, S. C. Kim, M. Song, J. Lee, W. Shin, S.-J. Moon, J. H. Bahng, N. A. Kotov and S.-H. Jin, *ACS Nano*, 2011, **5**, 3319.
- F. C. Krebs, S. A. Gevorgyan and J. Alstrup, *J. Mater. Chem.*, 2009, **19**, 5442.
- F. C. Krebs, *Sol. Energy Mater. Sol. Cells*, 2009, **93**, 1636.
- J. N. Israelachvili, *Intermolecular and surface forces*, Academic Press, London 1992.
- Y. Xiong, I. Washio, J. Chen, H. Cai, Zhi.-Y. Li and Y. Xia, *Langmuir*, 2006, **22**, 8563.